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Synthesis of nitrogen-doped graphene via thermal treatment of graphene oxide within methylimidazole and its capacitance performance as electric double layer capacitor

Abstract

Nitrogen-doped graphene was successfully synthesised from graphene oxide (GO) and 2-methylimidazole composite via thermal treatment under argon flow at 700°C within 1h. This synthesised N-doped graphene exhibits homogeneous nitrogen doping with concentration of ~5% in three different nitrogen configuration namely pyridinic N, pyrrolic N and graphitic N. The electric double layer capacitor (EDLC) made up with this N-doped graphene showed excellent specific capacitance 274 F/g at current density of 1A/g, which was ~7 times higher than GO. This EDLC capacitor showed excellent cyclic stability up to 5000 cycles with capacity retention of ~91%.

Keywords

methylimidazole, within, oxide, synthesis, nitrogen, capacitor, capacitance, treatment, electric, thermal, its, via, performance, doped, double, graphene, layer

Disciplines

Engineering | Physical Sciences and Mathematics

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Research Article

Synthesis of Nitrogen-Doped Graphene via Thermal Treatment of Graphene Oxide within Methylimidazole and its Capacitance Performance as Electric Double Layer Capacitor

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Abstract

Nitrogen-doped graphene was successfully synthesised from graphene oxide (GO) and 2-methylimidazole composite via thermal treatment under argon flow at 700°C within 1h. This synthesised N-doped graphene exhibits homogeneous nitrogen doping with concentration of ~5% in three different nitrogen configuration namely pyridinic N, pyrrolic N and graphitic N. The electric double layer capacitor (EDLC) made up with this N-doped graphene showed excellent specific capacitance 274 F/g at current density of 1A/g, which was ~7 times higher than GO. This EDLC capacitor showed excellent cyclic stability up to 5000 cycles with capacity retention of ~91%.

Introduction

Two dimensional single-layer nanostructure of sp^2 hybridized conjugated carbon atoms is termed as graphene^[1,2]. Graphene materials have attracted an interesting research topic which usually widely used in the area to prepared high performance electrode for capacitor due to its superior electrical, mechanical and thermal properties^[2-4]. Modification of graphene structure with hetero atoms can tremendously change the electronic properties with can enhance its performance in the diversity fields of applications^[5]. Commonly used heteroatom namely S, N, P and B-doped graphene reported in the literature^[6-8]. Among them, recently N-doped graphene has attracted attentions due to its various applications^[9,10]. The doping of nitrogen (N) atom in graphene structure can enhance the electron mobility which leads to a larger capacitance because of its strong valance bond and atomic size^[11]. Nitrogen doping in graphene structure easily influence the local electronic structures^[12,13] which help to improves the device performance in many types of applications including fuel cells^[14], electronic devices^[15] and biosensors^[16].

N-doped graphene can be synthesised in various pathways such as nitrogen plasma process^[17,9], arc-discharge^[18], segregation growth^[19], chemical vapour deposition (CVD)^[20,21], thermal annealing^[22,23], and hydrothermal process^[24,25]. Among these process, the thermal annealing of graphene oxide with a solid source of nitrogen are attractive because they can be scaled up without any catalyst^[26]. On the other hand, most of the other techniques use gaseous or liquid sources of nitrogen to synthesis nitrogen doped graphene, and the method also suffers from practical limitations due to possible contamination from the metal deposition catalyst as well as the toxicity of the precursors.

In this work we prepared nitrogen doped graphene using a solid nitrogen precursors 2-methylimidazole via thermal treatment under argon flow. To the best of our knowledge, we are the first time reporting N-doped graphene using 2-methylimidazole precursors. In this process graphene oxide (GO) and 2-methylimidazole composite were heated up to 700°C for 1h to get N-doped graphene which shows excellent capacitance properties as electric double layer capacitor (EDLC).

Experiment

Graphene oxide (GO) was synthesised according to the literature reported method^[27]. In details, graphite flakes (Asbury Carbons, Carbon content: 99%) were put in a ceramic boat and then placed in tube furnace at 1050°C for 15second to get thermally expanded graphite. Then 2gm of expandable graphite and 250mL of H_2SO_4 (98%, Sigma Aldrich) were taken in a three neck flask and stirred for 24h at room temperature. After that, 6 gm of $KMnO_4$ (99%, Sigma Aldrich) added slowly under continuous stirring. Then the solution mixture was kept 24h under stirring. The mixture was then taken under ice bath and 250mL deionised water and 60mL of H_2O_2 (30%, Sigma Aldrich) were drop wise added in the mixture under stirring. The resulting solution mixture changes the colour to light brown. Finally GO dispersion was washed 3 times with HCl solution ($9H_2O:1HCl$ vol%) at 6000rpm centrifugation process. The GO precipitation was washed 10 times with water till to get pH =6. Then the GO was collected and dried at 80°C in vacuum oven for 12h.

Nitrogen-doped graphene was synthesised from GO-methylimidazole composite materials. For making this composite, 70mg GO and 30mg 2-methylimidazole (Sigma-Al-

drich, 99%) was mixed in 50mL H₂O and then it was dispersed under sonication for 1h. Then the solution mixture was heated upto 80°C for 12h under stirring till to remove the water. Then the final solids (GO-methylimidazole composite) were collected and put ceramic quartz boat. Then the ceramic boat was placed in tube furnace at 700°C under argon flow for 1h. Then the final product stored as nitrogen doped graphene.

The phase structures of synthesized graphene materials were examined by X-ray diffraction (XRD, GBC MMA, CuK α radiation, $\lambda = 0.154$ nm). The morphology of the materials and Energy dispersive spectroscopy (EDS) mapping of element present in N-doped graphene were observed by field emission electron microscope (FE-SEM, JEOL JSM-7500FA), the surface chemical compositions were analysis by X-ray photoelectron spectroscopy (XPS, SPECS GmbH). Raman spectroscopy (Renishaw) was performed at $\lambda = 514.5$ nm). The transmission electron microscopy (TEM) was examined by JEOL F3000 instrument.

All the electrochemical characterization of the electric double layer capacitor (EDLC) was performed by VMP3 Bio-Logic electrochemical workstation. Then cyclic voltammograms (CVs) and galvanostatic charge-discharge were measured at scan rate of 100mV/s and current density of 1 A/g respectively. The electrochemical impedance spectroscopy (EIS) measurement was performed at room temperature where the frequency range spanned 100kHz to 0.01Hz. For making EDLC device, two gold coins (15mm in diameter) were used as electrodes and the coated electrode were separated by glass fiber separator. The separator was placed between the coated electrodes that were pressed together at high pressure and 0.5M H₂SO₄ was used as electrolyte in the air tight cell. The electrode was prepared by loading 90% active material and 10% PTFE (polytetrafluoroethylene) binder. 0.5mg active materials were deposited on the each gold electrode surface using a 10wt% PTFE binder. The total loading of the active materials of the cell was 1mg. Capacitance was calculated from CV by the following equation^[28]. Capacitance, $C = 4 \times (\text{Current} / \text{Scan rate})$, where Current = $(|I_a| + |I_c|)/2$, I_a = anodic current and I_c = cathodic current. Specific capacitance calculated by the following equation: $C_s = C/m$, Where m is the total weight of active material of two electrodes. The gravimetric capacitance from galvanostatic charge/discharge was calculated using the following equation^[29,30].

$$C_s = \frac{4I}{m \frac{dV}{dt}}$$

Where C_s is specific capacitance (F/g), I is the charge/discharge current density (A/g), m is the total mass of materials deposited on the two electrodes and dV/dt was calculated from the slope of the discharge curve.

Result and Discussion

Graphene oxide (GO) and N-doped graphene were characterized by X-ray diffraction. It can be observed from (Figure 1), GO showed peak at $2\theta = 11.6^\circ$ which is very close to the reported XRD pattern of GO^[31]. On the other hand, after thermal treatment of GO- methylimidazole composite, the XRD peak position shifted to $2\theta = 26.3^\circ$ similar to the XRD peak position of N-doped graphene^[31]. That result illustrates that the

d_{spacing} of GO ($d = 0.762$ nm) is decreasing after thermal treatment of GO-methylimidazole composite, that means a significant removal of oxygen groups was occurred during the process and GO was reduced into the N-doped graphene ($d = 0.336$ nm)^[32]. In addition, the peak of N-doped graphene at $2\theta = 26.3^\circ$ with broader width and weaker intensity than pristine graphene oxide ($2\theta = 11.6^\circ$) is due to the defect produced by the insertion of nitrogen atom and carbon atom loss destroy the graphite crystal structure that means the degree of disorder increased within the graphene sheet. The decreasing of the oxygen group can be easily understood from the XPS analysis. (Figure 2a) showed the XPS spectrum of GO which composed of two elements C and O; on the other hand after thermal treatment of GO-methylimidazole, three elements C, O and N was found (Figure 2b). C and O content was found 65.1% and 34.8% respectively in GO materials, and 88.1% C and 7.0% O was found in after thermal annealing of the GO-methylimidazole composite. The C/O ratio ($=1.86$) of GO was increased much after thermal treatment of the composite and was reached to 12.56 which demonstrate the reduction of GO and the presence of N means the successful preparation of N-doped graphene.

Table 1. Chemical composition and capacitance performance of graphene oxide (GO) and N-doped graphene

Materials	Surface chemical concentration (at%) ^a				Capacitance ^b (F/g)
	C	O	N	C/O	
GO	65.13	34.87	- ^c	1.87	38
N-doped graphene	88.10	7.01	4.89	12.56	274

^aCalculated from XPS analysis refer to Figure: 2;

^bCalculated from galvanostatic charge-discharge profile refer to Figure 9b;

^cNot detected.

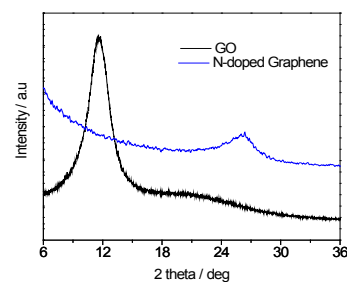


Figure 1: X-ray diffraction patterns: (a) graphene oxide (GO); (b) nitrogen-doped graphene after thermal treatment of graphene oxide and 2-methylimidazole composite at 700°C for 1h

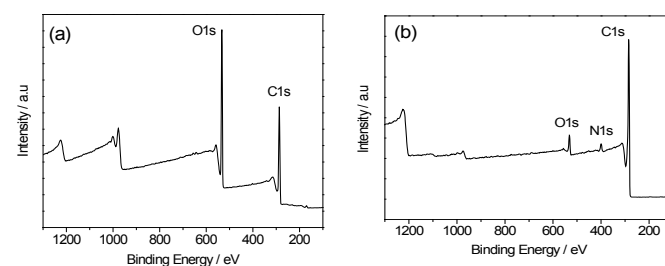


Figure 2: X-ray photoelectron spectra: (a) GO; (b) N-doped graphene;

The morphology of these two materials (GO and N-doped graphene) were observed by SEM. From the SEM image (Figure 3), it can be seen that the GO sheets were found more stacking of sheets, but the N-doped graphene sheets were more

separated flake like a good lamellar structure, and rich wrinkles structures on the surface for the usual N-doped graphene^[31]. The TEM images of GO and N-doped graphene exhibit a sheet like structure. GO exhibit more likely agglomerated with multiple sheets than that of N-doped graphene. It can be clearly found from its corresponding selected area diffraction pattern (SAED). Its SAED pattern of GO (Figure 4a) shows concentric rings masked with bright many spots demonstrating it to be of polycrystalline nature with multiple layers of graphene sheet. On the contrary, SAED pattern of N-doped graphene (Figure 4b) clearly shows the nature of graphene sheets to be crystalline with six fold symmetry illustrated the single layer graphene structure.

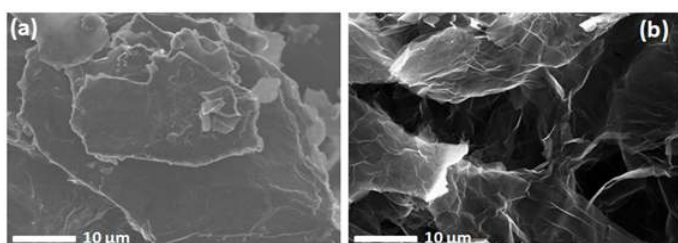


Figure 3: SEM images: (a) GO; (b) N-doped graphene.

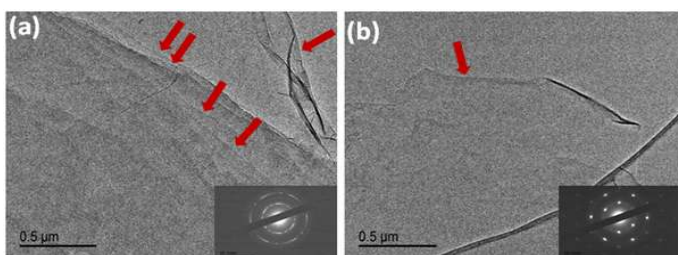


Figure 4: TEM images (inset SAED): (a) GO and (b) N-doped graphene.

The bonding configurations of nitrogen atom within the carbon lattice in the structural carbon materials are mainly three types^[33] quaternary N (or graphitic N), pyridinic N, and pyrrolic N (Figure 5). When the N atoms that substitute C atoms in the hexagonal rings are termed as quaternary nitrogen. Pyridinic nitrogen refers to the nitrogen that bond with two C atoms at the edge of the hexagonal ring that contribute one p electron to the π system. Pyrrolic nitrogen bonds into the five-membered ring like pyrrole that contribute two p electron into the π system^[33]. The types of doped nitrogen in our synthesised N-doped graphene was observed from the deconvoluted N1s region of XPS spectrum (Figure 6). N1s spectrum showed three individual peaks at binding energy at 398.3, 400.1 and 401.6 eV which is attributed to pyridinicN, pyrrolic N and quaternary N^[33]. This result illustrates the doping of nitrogen atom in the synthesised N-doped graphene structure. The homogeneous doping of nitrogen was confirmed by electron dispersive elemental mapping (Figure 7). GO, and the N-doped graphene were characterized by Raman spectroscopy. As shown in (Figure 8), the G peaks of the GO and N-doped graphene occurred at 1588 and 1582 cm^{-1} . The G peaks shifted to lower energy from GO to N-doped graphene, indicating that a conjugated sp^2 structure was restored during thermal treatment^[34]. The I_D/I_G ratios of GO and N-doped graphene were 0.89 and 1.04 respectively, which were used to calculate the defects or in-plane crystallite size after thermal treatment, calculated according to the Tuinstra–Koenig (TK) relation:

$$L_a = (2.4 \times 10^{-10}) \lambda^4 (I_D/I_G)^{-1}$$

Where L_a is the crystallite sizes, λ is the Raman excitation wavelength (514 nm). The crystallite sizes of N-doped graphene ($L_a = 16.1$) was smaller than that of GO ($L_a = 18.8$) indicating that the crystallite sizes decreased upon thermal treatment.

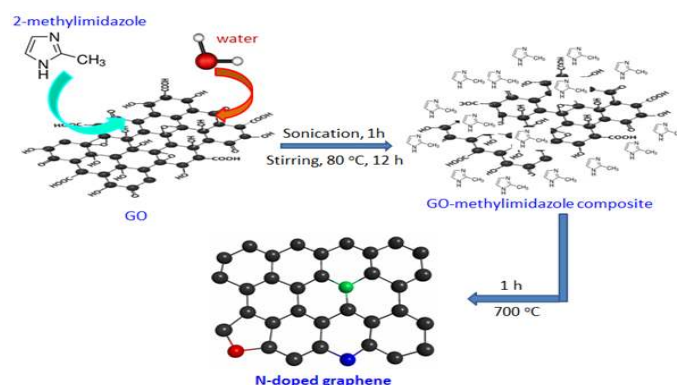


Figure 5 : Synthesis process of nitrogen-doped graphene, and illustration of of types nitrogen configurations in N-doped graphene. Green, blue and red colour represents graphitic N, pyridinic N and pyrrolic N respectively.

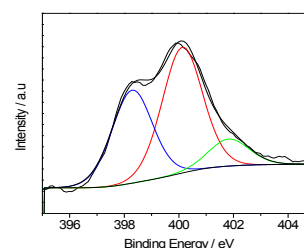


Figure 6: XPS deconvoluted N1s regions of N-doped graphene.

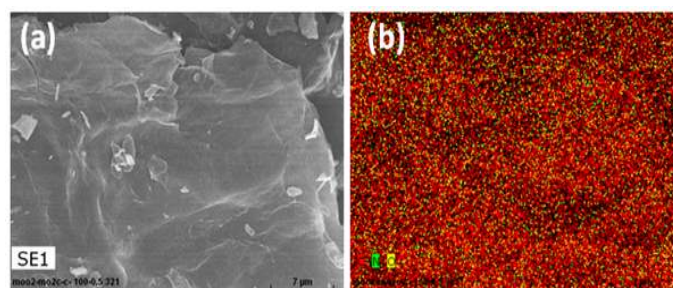


Figure 7: SEM image of N-doped graphene with its corresponding EDS elemental mapping of carbon (red), oxygen (yellow) and nitrogen (green).

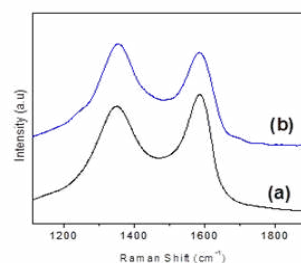


Figure 8: Raman spectra: (a) GO and (b) N-doped graphene

Our synthesised two materials (GO and N-doped graphene) should have some differences in terms of capacitance properties as these two materials have differences in structural chemical composition. To observed the capacitance properties, electrode for double layer capacitor (EDLC) was made by GO and N-doped graphene. At first the EDLC was tested by cyclic

voltammetric (CV) techniques. The (Figure 9a) showed the cyclic voltammograms (CVs) of N-doped graphene and graphene oxide (GO). It illustrated that N-doped graphene showed much current response than GO at scan rate of 100 mV/s. The gravimetric capacitance for GO and N-doped graphene is 44 F/g and 209 F/g respectively. Capacitance of N-doped graphene is about 4 times higher than that of GO, and the rectangular shape of CV for N-doped graphene showed the ideal characteristics of double layer capacitor^[35]. In terms of practical application galvanostatic charge–discharge (CD) curves is the best way to measure the capacitance for actual electrode materials^[36]. It also found the big difference between two materials by galvanostatic charge–discharge curves (Figure 9b). The linear regular symmetrical triangle CD curve and the longer time in CD cycle of N-doped graphene, indicates the highest capacitance for N-doped graphene than GO. The capacitance was measured from CD curves and it was 38 F/g and 274 F/g at current density of 1 A/g for GO and N-doped graphene respectively. The dramatic enhancement of capacitance for N-doped graphene is due to the doing of nitrogen in the structure of graphene; on the contrary GO was lack of nitrogen. According to the CD profile capacitance of N-doped graphene is 7 times higher than GO. The specific capacitance of this N-doped graphene is higher than N-doped graphene synthesized using literature reported precursors cyanamide^[37], pyrrole^[38] and urea^[39]. The main reason of this big difference usually for N-doping configuration in N-doped graphene. The both quantum mechanical calculations^[9,40] and experimental^[41,42] investigations indicate that graphitic, pyridinic and pyrrolic N can enhance the capacitance.

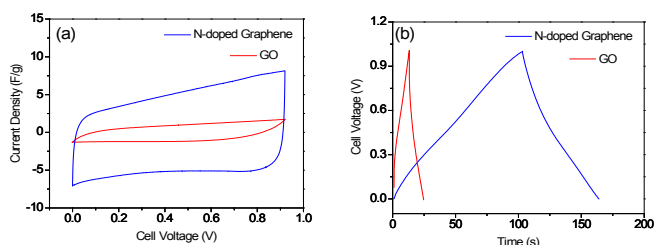


Figure 9: (a) Cyclic voltammograms (CVs) of GO and N-doped graphene EDLC device measured in 0.5 M H₂SO₄ at scan rate of 100 mV/s; (b) Galvanostatic charge-discharge profile of GO and N-doped graphene EDLC device measured in 0.5 M H₂SO₄ at current density of 1 A/g.

The cyclic stability of EDLC is very important for practical application. The capability of the electrode of EDLC device made by N-doped graphene electrodes was carried out by using galvanostatic charge discharge techniques at current density of 1 A/g (Figure 10a). It showed excellent cyclic stability up to long 5000 cycles and the capacity retention was found ~89% which is significant for an ideal capacitor (Figure 10b).

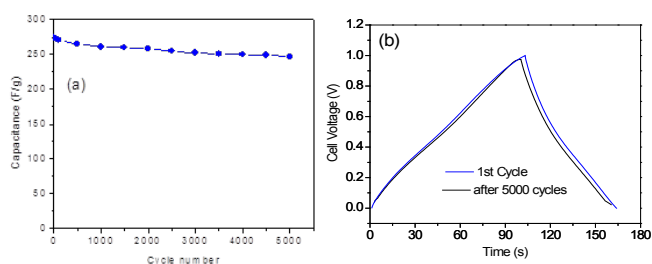


Figure 10: (a) Cycle performance of EDLC capacitor fabricated with N-doped graphene measured at 1 A/g; (b) Comparative galvanostatic charge-discharge profile between 1st cycle and after 5000th cycles.

Conclusion

In summary, nitrogen doped graphene was successfully synthesised using 2-methylimidazole as a nitrogen source for doping in graphene oxide via thermal annealing. This process was very simple and one step to synthesis N-doped graphene. The concentration of nitrogen was found ~5% with three configurations of nitrogen species. The electric double layer capacitor made up with this N-doped graphene showed high specific capacitance 274 F/g at current density of 1 A/g which is ~7 times higher than GO. This capacitor showed excellent cyclic stability with capacity retention of ~91% after 5000 cycles.

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